

# SiT5001

## 1-80 MHz MEMS TCXO and VCTCXO



### Features

- Any frequency between 1 and 80 MHz accurate to 6 decimal places
- 100% pin-to-pin drop-in replacement to quartz-based (VC)TCXO
- Frequency stability as low as  $\pm 5$  ppm. Contact SiTime for tighter stability options
- Ultra low phase jitter: 0.5 ps (12 kHz to 20 MHz)
- Voltage control option with pull range from  $\pm 12.5$  ppm to  $\pm 50$  ppm
- LVC MOS compatible output with SoftEdge™ option for EMI reduction
- Voltage control, standby, output enable or no connect modes
- Standard 4-pin packages: 2.5 x 2.0, 3.2 x 2.5, 5.0 x 3.2, 7.0 x 5.0 mm
- Outstanding silicon reliability of 2 FIT, 10 times better than quartz
- Pb-free, RoHs and REACH compliant

### Applications

- WiFi, 3G, LTE, SDI, Ethernet, SONET, DSL
- Telecom, networking, smart meter, wireless, test instrumentation



### Electrical Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Output Frequency Range	f	1	–	80	MHz	
Initial Tolerance	F_init	-1	–	1	ppm	At 25°C after two reflows
Stability Over Temperature	F_stab	-5	–	+5	ppm	Over operating temperature range at rated nominal power supply voltage and load. (see ordering codes on page 6) <b>Contact SiTime for tighter stability options.</b>
Supply Voltage	F_vdd	–	50	–	ppb	$\pm 10\%$ Vdd ( $\pm 5\%$ for Vdd = 1.8V)
Output Load	F_load	–	0.1	–	ppm	15 pF $\pm 10\%$ of load
First year Aging	F_aging	-2.5	–	+2.5	ppm	25°C
10-year Aging		-4.0	–	+4.0	ppm	25°C
Operating Temperature Range	T_use	-20	–	+70	°C	Extended Commercial
		-40	–	+85	°C	Industrial
Supply Voltage	Vdd	1.71	1.8	1.89	V	Contact SiTime for any other supply voltage options.
		2.25	2.5	2.75	V	
		2.52	2.8	3.08	V	
		2.70	3.0	3.3	V	
		2.97	3.3	3.63	V	
Pull Range	PR	$\pm 12.5, \pm 25, \pm 50$			ppm	
Upper Control Voltage	VC_U	Vdd-0.1	–	–	V	All Vdds. Voltage at which maximum deviation is guaranteed.
Control Voltage Range	VC_L	–	–	0.1	V	
Control Voltage Input Impedance	Z_vc	100	–	–	k $\Omega$	
Frequency Change Polarity	–	Positive slope			–	
Control Voltage -3dB Bandwidth	V_BW	–	–	8	kHz	
Current Consumption	Idd	–	31	33	mA	No load condition, f = 20 MHz, Vdd = 2.5V, 2.8V or 3.3V.
		–	29	31	mA	No load condition, f = 20 MHz, Vdd = 1.8V.
OE Disable Current	I_OD	–	–	31	mA	Vdd = 2.5V, 2.8V or 3.3V, OE = GND, output is Weakly Pulled Down
		–	–	30	mA	Vdd = 1.8 V. OE = GND, output is Weakly Pulled Down
Standby Current	I_std	–	–	70	$\mu$ A	Vdd = 2.5V, 2.8V or 3.3V, $\overline{ST}$ = GND, output is Weakly Pulled Down.
		–	–	10	$\mu$ A	Vdd = 1.8V. $\overline{ST}$ = GND, output is Weakly Pulled Down.
Duty Cycle	DC	45	–	55	%	All Vdds
LVC MOS Rise/Fall Time	Tr, Tf	–	1.5	2	ns	LVC MOS option. Default rise/fall time, All Vdds, 10% - 90% Vdd.
SoftEdge™ Rise/Fall Time		SoftEdge™ Rise/Fall Time Table			ns	SoftEdge™ option. Frequency and supply voltage dependent.
Output Voltage High	VOH	90%	–	–	Vdd	OH = -7 mA, IOL = 7 mA, (Vdd = 3.3V, 3.0V)
Output Voltage Low	VOL	–	–	10%	Vdd	IOH = -4 mA, IOL = 4 mA, (Vdd = 2.8V, 2.5V)
						IOH = -2 mA, IOL = 2 mA, (Vdd = 1.8V)
Input Voltage High	VIH	70%	–	–	Vdd	Pin 1, OE or $\overline{ST}$
Input Voltage Low	VIL	–	–	30%	Vdd	Pin 1, OE or $\overline{ST}$
Input Pull-up Impedance	Z_in	–	100	250	k $\Omega$	

### Electrical Characteristics (continued)

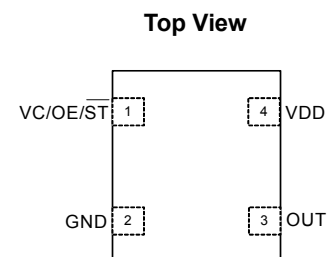
Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Startup Time	T_start	–	–	10	ms	Measured from the time Vdd reaches its rated minimum value
OE Enable/Disable Time	T_oe	–	–	150	ns	f = 80 MHz. For other frequencies, T_oe = 100 ns + 3 cycles
Resume Time	T_resume	–	6	10	ms	Measured from the time ST pin crosses 50% threshold
RMS Period Jitter	T_jitt	–	1.7	2	ps	f = 10 MHz, Vdd = 2.5V, 2.8V or 3.3V
		–	1.7	2	ps	f = 10 MHz, Vdd = 1.8V
RMS Phase Jitter (random)	T_phj	–	0.5	1	ps	f = 10 MHz, Integration bandwidth = 12 kHz to 20 MHz, All Vdds

**Note:**

- All electrical specifications in the above table are measured with 15pF output load, Contact SiTime for higher drive options.

### Pin Configuration

Pin	Symbol	Functionality	
1	VC/OE/ $\overline{ST}$ /NC	V control	Voltage control
		Output Enable	H or Open <sup>[2]</sup> : specified frequency output L: output is high impedance. Only output driver is disabled.
		Standby	H or Open <sup>[2]</sup> : specified frequency output L: output is low (weak pull down). Device goes to sleep mode. Supply current reduces to I_std.
		NC	No connect (input receiver off)
2	GND	Power	Electrical and case ground
3	CLK	Output	Oscillator output
4	VDD	Power	Power supply voltage



**Note:**

- A pull-up resistor of <10 k $\Omega$  between OE/ $\overline{ST}$  pin and Vdd is recommended in high noise environment when the device operates in OE/ $\overline{ST}$  mode.

### Absolute Maximum

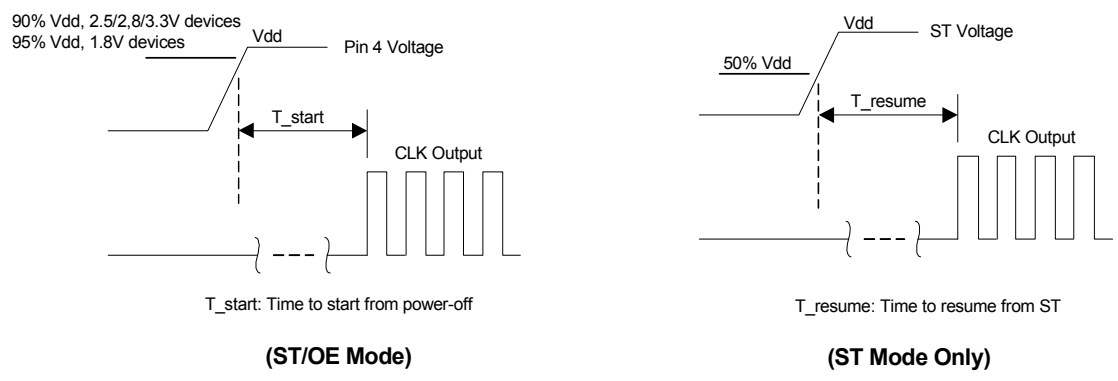
Attempted operation outside the absolute maximum ratings of the part may cause permanent damage to the part. Actual performance of the IC is only guaranteed within the operational specifications, not at absolute maximum ratings.

Parameter	Min.	Max.	Unit
Storage Temperature	-65	150	°C
VDD	-0.5	4	V
Electrostatic Discharge	–	2000	V
Soldering Temperature (follow standard Pb free soldering guidelines)	–	260	°C

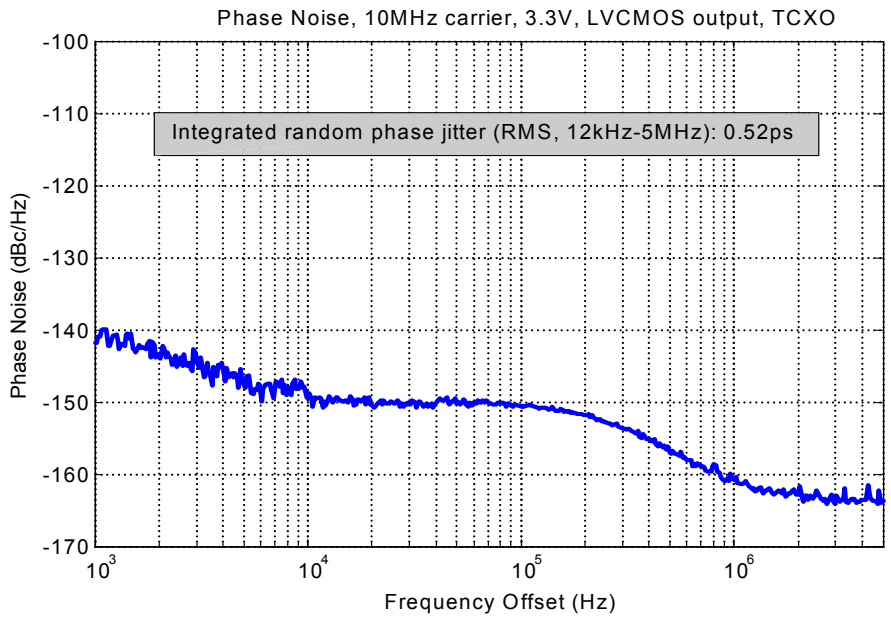
### Environmental Compliance

Parameter	Condition/Test Method
Mechanical Shock	MIL-STD-883F, Method 2002
Mechanical Vibration	MIL-STD-883F, Method 2007
Temperature Cycle	JESD22, Method A104
Solderability	MIL-STD-883F, Method 2003
Moisture Sensitivity Level	MSL1 @ 260°C

### Timing Diagram



### Phase Noise Plot



### SoftEdge™ Option

The SoftEdge™ output is available as a standard option for the SiT500x family of MEMS (VC)TCXOs. It is typically used for EMI reduction similar to that of the clipped sinewave output common to many quartz based TCXOs.

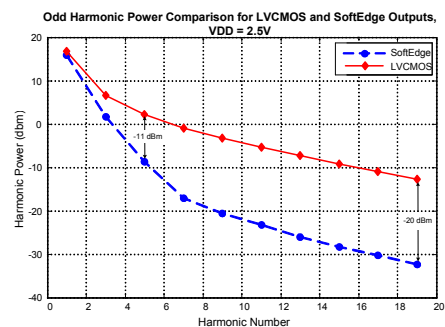
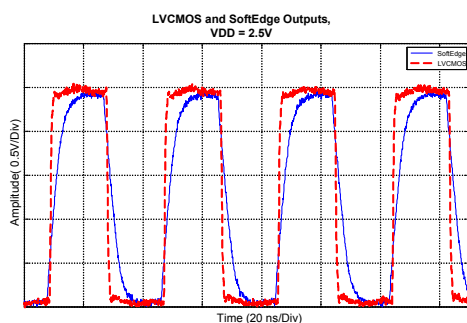
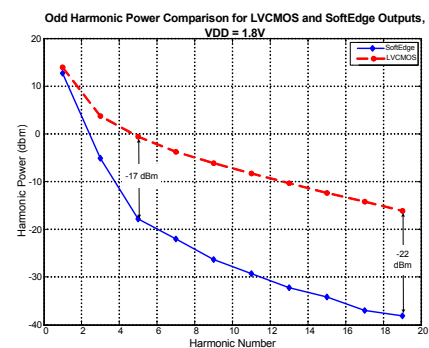
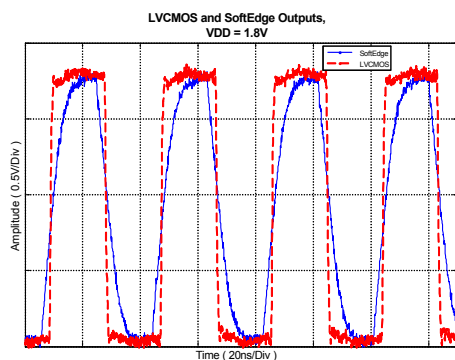
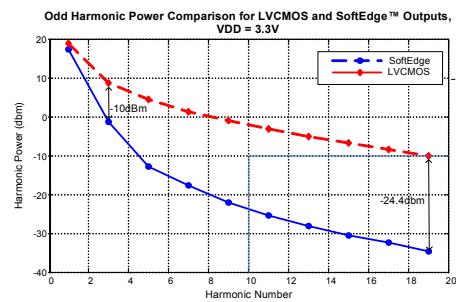
In the SoftEdge™ mode, the slower rise/fall edges of the output waveform reduce the higher clock harmonics in a digital clock signal, minimizing EMI radiation at these harmonics. The table below show the actual rise/fall time in relation to the desired output frequency and the supply voltage with a 10 kΩ / 10pF load. Rail-to-rail swing of the output is maintained for these supported frequencies.

### Rise/Fall Time for SoftEdge™ Option

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Rise/Fall Time	Tr, Tf	4.0	6.5	9.5	ns	1-26 MHz, 1.8V, 3.0 and 3.3V, MHz 10k and 10 pF, 20%-80% Vd
		2.5	4.0	6.0	ns	1-26 MHz, 2.5V and 2.8V, MHz 10k and 10 pF, 20%-80% Vdd
		1.5	3.5	5.0	ns	26-50 MHz, 1.8V, 3.0V and 3.3V, MHz 10k and 10 pF, 20%-80% Vdd
		1.5	2.5	4.5	ns	26-50 MHz, 2.5V and 2.8V, MHz 10k and 10 pF, 20%-80% Vdd

### SoftEdge™ Waveform Examples and Corresponding Harmonics Reduction

Figures below illustrate the harmonic power reduction as the rise/fall times are slowed from the standard squarewave output to that of the SoftEdge™ output. In general, the 1.8V device shows the lowest harmonics and provides best EMI performance comparing to devices with higher operating voltages.



### Dimensions and Patterns

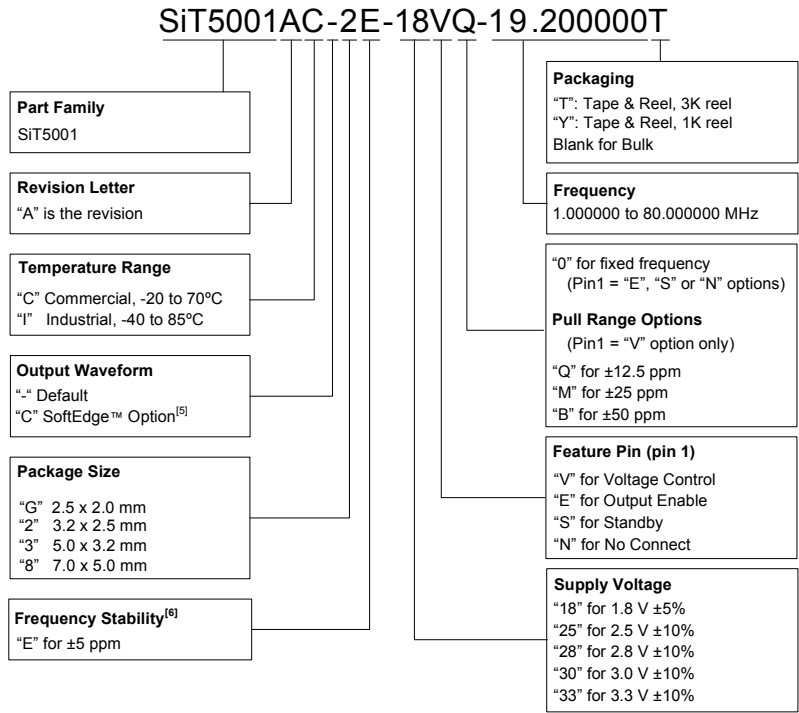
Package Size – Dimensions (Unit: mm) <sup>[3]</sup>	Recommended Land Pattern (Unit: mm) <sup>[4]</sup>
<p><b>2.7 x 2.4 x 0.75 mm (100% compatible with 2.5 x 2.0 mm footprint)</b></p>  <p>Top view dimensions: 2.7 ± 0.05 mm (width), 2.4 ± 0.05 mm (height). Pin locations: #1 (bottom-left), #2 (bottom-right), #3 (top-right), #4 (top-left). Marking: YXXXX with a small circle below the 'Y'. Bottom view dimensions: 0.75 ± 0.05 mm (height). Land pattern dimensions: 1.9 mm (width), 1.5 mm (height), 1.1 mm (width), 1.0 mm (height).</p>	 <p>Land pattern dimensions: 1.9 mm (width), 1.5 mm (height), 1.1 mm (width), 1.0 mm (height).</p>
<p><b>3.2 x 2.5 x 0.75 mm</b></p>  <p>Top view dimensions: 3.2 ± 0.05 mm (width), 2.5 ± 0.05 mm (height). Pin locations: #1 (bottom-right), #2 (bottom-left), #3 (top-left), #4 (top-right). Marking: YXXXX with a small circle below the 'Y'. Bottom view dimensions: 0.75 ± 0.05 mm (height). Land pattern dimensions: 2.2 mm (width), 1.9 mm (height), 1.4 mm (width), 1.2 mm (height).</p>	 <p>Land pattern dimensions: 2.2 mm (width), 1.9 mm (height), 1.4 mm (width), 1.2 mm (height).</p>
<p><b>5.0 x 3.2 x 0.75 mm</b></p>  <p>Top view dimensions: 5.0 ± 0.05 mm (width), 3.2 ± 0.05 mm (height). Pin locations: #1 (bottom-right), #2 (bottom-left), #3 (top-left), #4 (top-right). Marking: YXXXX with a small circle below the 'Y'. Bottom view dimensions: 0.75 ± 0.05 mm (height). Land pattern dimensions: 2.54 mm (width), 2.2 mm (height), 1.5 mm (width), 1.6 mm (height).</p>	 <p>Land pattern dimensions: 2.54 mm (width), 2.2 mm (height), 1.5 mm (width), 1.6 mm (height).</p>
<p><b>7.0 x 5.0 x 0.90 mm</b></p>  <p>Top view dimensions: 7.0 ± 0.05 mm (width), 5.0 ± 0.05 mm (height). Pin locations: #1 (bottom-right), #2 (bottom-left), #3 (top-left), #4 (top-right). Marking: YXXXX with a small circle below the 'Y'. Bottom view dimensions: 0.90 ± 0.10 mm (height). Land pattern dimensions: 5.08 mm (width), 3.81 mm (height), 2.2 mm (width), 2.0 mm (height).</p>	 <p>Land pattern dimensions: 5.08 mm (width), 3.81 mm (height), 2.2 mm (width), 2.0 mm (height).</p>

**Notes:**

- 3. Top marking: Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device.
- 4. A capacitor of value 0.1 μF between Vdd and GND is recommended.

### Ordering Information

The Part No. Guide is for reference only. To customize and build an exact part number, use the SiTime [Part Number Generator](#).



**Notes:**

- 5. SiTime's SoftEdge™ output waveform with 6 ns rise/fall time reduces EMI and is similar to clipped sine wave in functionality.
- 6. Contact SiTime for tighter stability options.

### Additional Information

Document	Description	Download Link
<b>Manufacturing Notes</b>	Tape & Reel dimension, reflow profile and other manufacturing related info	<a href="http://www.sitime.com/component/docman/doc_download/85-manufacturing-notes-for-sitime-oscillators">http://www.sitime.com/component/docman/doc_download/85-manufacturing-notes-for-sitime-oscillators</a>
<b>Qualification Reports</b>	RoHS report, reliability reports, composition reports	<a href="http://www.sitime.com/support/quality-and-reliability">http://www.sitime.com/support/quality-and-reliability</a>
<b>Performance Reports</b>	Additional performance data such as phase noise, current consumption and jitter for selected frequencies	<a href="http://www.sitime.com/support/performance-measurement-report">http://www.sitime.com/support/performance-measurement-report</a>
<b>Termination Techniques</b>	Termination design recommendations	<a href="http://www.sitime.com/support/application-notes">http://www.sitime.com/support/application-notes</a>
<b>Layout Techniques</b>	Layout recommendations	<a href="http://www.sitime.com/support/application-notes">http://www.sitime.com/support/application-notes</a>

### Revision History

Version	Release Date	Change Summary
1.0	11/12/15	Final production release <ul style="list-style-type: none"> <li>• Revised initial tolerance, stability over temperature and first/10 year aging values in the electrical characteristics table</li> <li>• Revised frequency stability option</li> </ul>

© SiTime Corporation 2015. The information contained herein is subject to change at any time without notice. SiTime assumes no responsibility or liability for any loss, damage or defect of a Product which is caused in whole or in part by (i) use of any circuitry other than circuitry embodied in a SiTime product, (ii) misuse or abuse including static discharge, neglect or accident, (iii) unauthorized modification or repairs which have been soldered or altered during assembly and are not capable of being tested by SiTime under its normal test conditions, or (iv) improper installation, storage, handling, warehousing or transportation, or (v) being subjected to unusual physical, thermal, or electrical stress.

**Disclaimer:** SiTime makes no warranty of any kind, express or implied, with regard to this material, and specifically disclaims any and all express or implied warranties, either in fact or by operation of law, statutory or otherwise, including the implied warranties of merchantability and fitness for use or a particular purpose, and any implied warranty arising from course of dealing or usage of trade, as well as any common-law duties relating to accuracy or lack of negligence, with respect to this material, any SiTime product and any product documentation. Products sold by SiTime are not suitable or intended to be used in a life support application or component, to operate nuclear facilities, or in other mission critical applications where human life may be involved or at stake. All sales are made conditioned upon compliance with the critical uses policy set forth below.

**CRITICAL USE EXCLUSION POLICY**  
 BUYER AGREES NOT TO USE SITIME'S PRODUCTS FOR ANY APPLICATION OR IN ANY COMPONENTS USED IN LIFE SUPPORT DEVICES OR TO OPERATE NUCLEAR FACILITIES OR FOR USE IN OTHER MISSION-CRITICAL APPLICATIONS OR COMPONENTS WHERE HUMAN LIFE OR PROPERTY MAY BE AT STAKE.

SiTime owns all rights, title and interest to the intellectual property related to SiTime's products, including any software, firmware, copyright, patent, or trademark. The sale of SiTime products does not convey or imply any license under patent or other rights. SiTime retains the copyright and trademark rights in all documents, catalogs and plans supplied pursuant to or ancillary to the sale of products or services by SiTime. Unless otherwise agreed to in writing by SiTime, any reproduction, modification, translation, compilation, or representation of this material shall be strictly prohibited.

# Supplemental Information

The Supplemental Information section is not part of the datasheet and is for informational purposes only.



# Silicon MEMS Outperforms Quartz

## Best Reliability

Silicon is inherently more reliable than quartz. Unlike quartz suppliers, SiTime has in-house MEMS and analog CMOS expertise, which allows SiTime to develop the most reliable products. Figure 1 shows a comparison with quartz technology.

### Why is SiTime Best in Class:

- SiTime’s MEMS resonators are vacuum sealed using an advanced EpiSeal™ process, which eliminates foreign particles and improves long term aging and reliability
- World-class MEMS and CMOS design expertise



Figure 1. Reliability Comparison<sup>[1]</sup>

## Best Aging

Unlike quartz, MEMS oscillators have excellent long term aging performance which is why every new SiTime product specifies 10-year aging. A comparison is shown in Figure 2.

### Why is SiTime Best in Class:

- SiTime’s MEMS resonators are vacuum sealed using an advanced EpiSeal process, which eliminates foreign particles and improves long term aging and reliability
- Inherently better immunity of electrostatically driven MEMS resonator

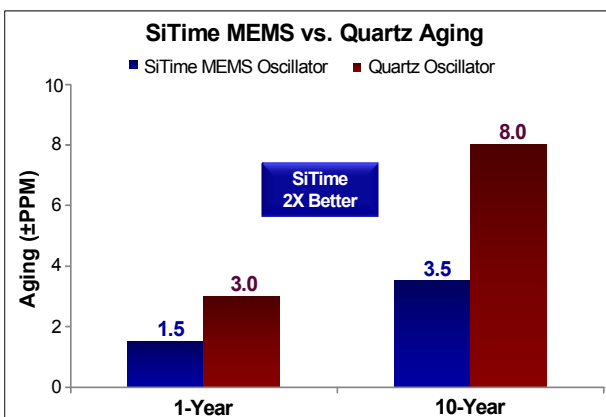


Figure 2. Aging Comparison<sup>[2]</sup>

## Best Electro Magnetic Susceptibility (EMS)

SiTime’s oscillators in plastic packages are up to 54 times more immune to external electromagnetic fields than quartz oscillators as shown in Figure 3.

### Why is SiTime Best in Class:

- Internal differential architecture for best common mode noise rejection
- Electrostatically driven MEMS resonator is more immune to EMS



Figure 3. Electro Magnetic Susceptibility (EMS)<sup>[3]</sup>

## Best Power Supply Noise Rejection

SiTime’s MEMS oscillators are more resilient against noise on the power supply. A comparison is shown in Figure 4.

### Why is SiTime Best in Class:

- On-chip regulators and internal differential architecture for common mode noise rejection
- Best analog CMOS design expertise



Figure 4. Power Supply Noise Rejection<sup>[4]</sup>

## Best Vibration Robustness

High-vibration environments are all around us. All electronics, from handheld devices to enterprise servers and storage systems are subject to vibration. Figure 5 shows a comparison of vibration robustness.

### Why is SiTime Best in Class:

- The moving mass of SiTime’s MEMS resonators is up to 3000 times smaller than quartz
- Center-anchored MEMS resonator is the most robust design



Figure 5. Vibration Robustness<sup>[5]</sup>

## Best Shock Robustness

SiTime’s oscillators can withstand at least 50,000 g shock. They all maintain their electrical performance in operation during shock events. A comparison with quartz devices is shown in Figure 6.

### Why is SiTime Best in Class:

- The moving mass of SiTime’s MEMS resonators is up to 3000 times smaller than quartz
- Center-anchored MEMS resonator is the most robust design



Figure 6. Shock Robustness<sup>[6]</sup>

### Notes:

1. Data Source: Reliability documents of named companies.
2. Data source: SiTime and quartz oscillator devices datasheets.
3. Test conditions for Electro Magnetic Susceptibility (EMS):
  - According to IEC EN61000-4.3 (Electromagnetic compatibility standard)
  - Field strength: 3V/m
  - Radiated signal modulation: AM 1 kHz at 80% depth
  - Carrier frequency scan: 80 MHz – 1 GHz in 1% steps
  - Antenna polarization: Vertical
  - DUT position: Center aligned to antenna

**Devices used in this test:**

  - SiTime, SiT9120AC-1D2-33E156.250000 - MEMS based - 156.25 MHz
  - Epson, EG-2102CA 156.2500M-PHPAL3 - SAW based - 156.25 MHz
  - TXC, BB-156.250MBE-T - 3rd Overtone quartz based - 156.25 MHz
  - Kyocera, KC7050T156.250P30E00 - SAW based - 156.25 MHz
  - Connor Winfield (CW), P123-156.25M - 3rd overtone quartz based - 156.25 MHz
  - SiLabs, Si590AB-BDG - 3rd overtone quartz based - 156.25 MHz
4. 50 mV pk-pk Sinusoidal voltage.
 

**Devices used in this test:**

  - SiTime, SiT8208AI-33-33E-25.000000, MEMS based - 25 MHz
  - NDK, NZ2523SB-25.6M - quartz based - 25.6 MHz
  - Kyocera, KC2016B25MOC1GE00 - quartz based - 25 MHz
  - Epson, SG-310SCF-25M0-MB3 - quartz based - 25 MHz
5. **Devices used in this test:** same as EMS test stated in Note 3.
6. Test conditions for shock test:
  - MIL-STD-883F Method 2002
  - Condition A: half sine wave shock pulse, 500-g, 1ms
  - Continuous frequency measurement in 100 μs gate time for 10 seconds

**Devices used in this test:** same as EMS test stated in Note 3
7. Additional data, including setup and detailed results, is available upon request to qualified customers. Please contact [productsupport@sitime.com](mailto:productsupport@sitime.com).

# Document Feedback Form



SiTime values your input in improving our documentation. Click [here](#) for our online feedback form or fill out and email the form below to [productsupport@sitime.com](mailto:productsupport@sitime.com).

1. Does the Electrical Characteristics table provide complete information? Yes      No

If No, what parameters are missing?

---

2. Is the organization of this document easy to follow? Yes      No

If "No," please suggest improvements that we can make:

---

3. Is there any application specific information that you would like to see in this document? (Check all that apply)

EMI                      Termination recommendations                      Shock and vibration performance                      Other

If "Other," please specify:

---

4. Are there any errors in this document? Yes      No

If "Yes", please specify (what and where):

---

5. Do you have additional recommendations for this document?

---

Name \_\_\_\_\_

Title \_\_\_\_\_

Company \_\_\_\_\_

Address \_\_\_\_\_

City / State or Province / Postal Code / Country \_\_\_\_\_

Telephone \_\_\_\_\_

Application \_\_\_\_\_

Would you like a reply? Yes      No

Thank you for your feedback. Please click the email icon in your Adobe Reader tool bar and send to [productsupport@sitime.com](mailto:productsupport@sitime.com). Or you may use our [online feedback form](#).

## Данный компонент на территории Российской Федерации

### Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

### Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: [info@moschip.ru](mailto:info@moschip.ru)

Skype отдела продаж:

moschip.ru

moschip.ru\_4

moschip.ru\_6

moschip.ru\_9